

SM31EMHS Photoelectric Sensor – Opposed Mode Sensor (Emitter)



Technical data

Туре	SM31EMHS
ID no.	3026411
Optical data	
Function	Opposed mode sensor
Operating mode	Emitter
Light type	IR
Wavelength	880 nm
Range	03000 mm
Electrical data	
Operating voltage	1030 VDC
Residual ripple	< 10 % U _{ss}
No-load current	≤ 25 mA
Readiness delay	≤ 100 ms
Response time typical	< 0.3 ms
Setting option	Potentiometer
Mechanical data	
Design	Rectangular with thread, Mini Beam
Dimensions	Ø 18 x 53.3 x 12.3 x 30.7 mm
Housing material	Plastic, Thermoplastic material, Yellow
Lens	plastic, Acrylic
Electrical connection	Cable, 2 m, PVC
Number of cores	2
Core cross-section	0.5 mm ²
Ambient temperature	-20+70 °C
Protection class	IP67
Special features	Encapsulated
Excess gain indication	LED

Features

Cable, PVC, 2 m Protection class IP67 Operating voltage: 10...30 VDC

Wiring diagram



Functional principle

Opposed mode sensors consist of an emitter and receiver. They are installed opposite each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Opposed mode sensors are the most reliable photoelectric sensors for detection of opaque targets. An excellent contrast between light and dark conditions and an extremly high excess gain are typical of this sensing mode, thus allowing operation over larger distances and under difficult conditions.

Excess gain curve Excess gain in relation to the distance





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Tests/approvals	
MTTF	853 years acc. to SN 29500 (Ed. 99) 40 °C
Approvals	CE, cURus, CSA

Accessories

